# A tom istic Theory of Coherent Spin Transfer between M olecularly Bridged Quantum D ots

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T in e-resolved Faradary rotation experiments have demonstrated coherent transfer of electron spin between C dSe colloidal quantum dots coupled by conjugated molecules. We employ here a G reen's function approach, using semi-empirical tight-binding to treat the nanocrystalH am iltonian and Extended Huckel theory to treat the linking molecule H am iltonian, to obtain the coherent transfer probabilities from atom istic calculations, without the introduction of any new parameters. C alculations on 1,4-dithiolbenzene and 1,4-dithiolcyclohexane linked nanocrystals agree qualitatively with experiment and provide support for a previous transfer H am iltonian model. We nd a striking dependence on the transfer probabilities as a function of nanocrystal surface site attachment and linking molecule conformation. A dditionally, we predict quantum interference e ects in the coherent transfer probabilities for 2,7-dithiolnaphthalene and 2,6-dithiolnaphthalene linking molecules. We suggest possible experiments based on these results that would test the coherent, through-molecule transfer m echanism.

#### I. IN TRODUCTION

C olloidal sem iconductor nanocrystals have attracted attention not only because of their size tunable optical properties, but also because of the long-lived spin coherences resulting from full three-dimensional connement.[1] P otential spintronic and quantum computational applications[2, 3] have led to the development of optical techniques such as time-resolved Faraday rotation (TRFR) for the measurement and manipulation of single spins in these systems, [4, 5, 6] as well as to theoretical methods to describe these properties.[6, 7, 8, 9] W ith the spin properties of isolated nanocrystals reasonably well understood, attention has now turned to the study of spin in linked nanocrystals. O uyang and Aw schalom observed coherent transfer between 3.4 nm and 7.0 nm diameter colloidal C dSe coupled by 1,4dithiolbenzene.[10] E lectron spin polarization created by optical pumping of the larger nanocrystal is transfered \instantaneously" (within the experimental limitations) and coherently to the smaller nanocrystal. This transfer from lower band gap to larger band gap nanocrystal is evidence against Forster-like transferm echanism s.[11] O uyang and Aw schalom conclude from their TRFR measurements transfer e ciencies of 10% at T < 50K and of 20% at 75 T 250K, and attribute this temperature dependence to changes in the conformation of the linking molecules.

Meier et al. have developed a transfer Ham iltonian theory describing the TRFR signal as a function of a spin transfer probability and Heisenberg spin-exchange between the coupled nanocrystals.[12] They draw the important conclusion that the TRFR signal at a given probe frequency does not provide enough information to determ ine the spin transfer probability, and thus the increase in Faraday rotational signal observed experimentally and interpreted as an increase in spin transfer e ciency for higher temperatures may also result from increases in the incoherent transfer probability, that uses a sem is principal tight-binding theory for the treatment of the nanocrystals and Extended Huckel theory for the linking molecule. This microscopic approach allows us to calculate the coherent spin transfer for new classes of linking molecules, as well as to study the e ects of their molecular conformation in a system atic fashion. A dditionally, we explore the variability of the spin transfer due to the distribution of surface sites of the nanocrystal, which is a previously unrecognized factor in the construction of devices based on this system.

#### II. THEORY

#### A. Sem iem pirical H am iltonian C alculation

To treat the CdSe nanocrystals, we have used the orthogonal nearest-neighbor sp<sup>3</sup>s basis tight-binding (TB) approach, using the standard sem iem pirical matrix elements, [13] transformed from zinc blende to hexagonal crystal structure. [14]. These parameters have been shown previously to reproduce the optical [15] and magneto-optical [8] properties of this system. The surface sites of the nanocrystal are passivated with oxygen-like ligands to m in ic the TOPO ligands used experimentally.

Since the TB param eterization does not extend to carbon or hydrogen atom s, we have treated the linking m olecules using Extended Huckel theory (EHT).[16, 17] As in the TB m ethod used for the nanocrystal, EHT uses a basis of valence Slater orbitals. Follow ing R ef. 14, where the ionization energy of the cation was used to determ ine a consistent

energy scale for the C dS and C dSe TB param eterizations in order to produce a param eterization for  $C dS_x Se_{1 x}$ , we require the ionization energies (diagonal TB H am iltonian terms) of the S and Se atoms to be consistent between the TB and EHT schemes. This leads to a global shift of the EHT H am iltonian energies by 11.155 eV to make it consistent with the TB energy scale. The insensitivity of our results to the exact value of this shift is demonstrated in Section IIIA 2. An sp<sup>3</sup> Slater-orbital basis is used for the non-C d atoms (H, C, S), using the param eters of R ef. 18, and the sp<sup>3</sup>s Slater-orbital basis of R ef. 19 is used for the C d atoms. These calculations are performed using a modi ed version of the Y aehm op program .[18] For sim plicity, and for better com parison with the work of M eier et al.,[12] we have neglected the spin-orbit coupling of the linking m olecule. This may be justi ed by noting that the spin-orbit coupling constants for carbon and hydrogen atoms are sm all.[20] N onetheless, this could be included in future studies.[21, 22] A dditionally, our treatment considers only sm all applied m agnetic elds, such that Zeem an splitting of the nanocrystal and m olecule levels is sm all.

There are several possible alternatives to the present TB/EHT H am iltonian treatm ent that m ay be useful for future research on other molecularly linked nanocrystal system s. For silicon nanocrystals linked by hydrocarbon molecules, one could use the orthogonal nearest-neighbor tight-binding parameterizations developed for Si-C alloys.[23] Form etal nanocrystals, one m ight use the non-orthogonal tight binding method of Papaconstantopolous and cow orkers, [24, 25] com bined with either EHT [16] or a Harrison tight-binding parameterization [26] for the linking molecule. Additionally, one m ight use other sem iem pirical techniques from quantum chemistry, such as INDO/S.[27, 28]

#### B. Determ ination of the N anocrystal Surface Local D ensity of States

The transfer probability calculation, described below, requires the use of the local density of states (LDOS) for the molecular contact sites. Unlike in typical molecular electronics calculations, e.g., Ref. 29, in which the nal contact is taken to be part of a bulk lead and consequently the bulk DOS at the Fermi energy may be used, in our case the LDOS will be a function of the nanocrystal surface site connected to the linking molecule, and must be calculated explicitly. By calculating the G reen's function,  $G_{NC}$  (E), of the nanocrystal H am iltonian,  $H_{NC}$ ,

$$G_{NC}(E) = [(E + i)I H_{NC}]^{\perp}$$
(1)

(where  $i = \frac{p_{-1}}{1}$  and is in nitesmal), the LDOS, NC (E; j), for the basis orbital j is given simply by

$$h = i \\ M_{\rm NC} (E;j) = {}^{1} Im G_{\rm NC} (E)_{jj}; \qquad (2)$$

or alternatively by

$$g_{NC} (E;j) = Im G_{NC} (E)_{jj} :$$
(3)

A coording to previous experim ental[30, 31, 32, 33, 34] and theoretical[14] work, group VI elements (such as S and O) bond preferentially to the Cd atom surface sites on the nanocrystal. Consequently, this calculation is made for each of the  $sp^3s$  Cd basis orbitals on the 84 surface Cd sites of the 3.4 nm diameter nanocrystal, and for each of the  $sp^3s$  Cd basis orbitals on the 243 surface Cd sites of the 5.0 nm diameter nanocrystal, over energy intervals of E = 0.01 eV. We use the same nanocrystal structures as in our previous work.[8] This stage of the calculation is time consuming, since determining G (E) requires a matrix inversion for each value of E considered. However the results for a given nanocrystal are independent of the linking molecule, and thus need only be determined once and stored for future use. We also note that this process adds articial peaks in the band-gap region for the T (E) plots, which are due to surface states induced by the removal of the ligands for the calculation of G (E).

### C. Transfer P robability C alculation

Following the treatment of D atta, [35] we may express the G reen's function for the entire system as

$$G_{sys}(\mathbf{E};\mathbf{j};\mathbf{k}) = \mathbf{E}\mathbf{I} \quad H_{mol} \quad \mathop{\mathbb{R}_{NC1}}_{NC1}(\mathbf{E};\mathbf{j}) \quad \mathop{\mathbb{R}_{NC2}}_{NC2}(\mathbf{E};\mathbf{k}) \quad \mathbf{i}; \tag{4}$$

where the self energy for a given nanocrystal surface site atom ic orbital (AO) j, is given by

$$_{NC1}(E;j) = \sum_{NC1}^{Y} (j) g_{NC1}(E;j) NC1(j):$$
(5)

Here (j) is the portion of the Ham iltonian matrix between the nanocrystal surface site AO j and the linking molecule basis functions. These matrix elements are determined from the EHT calculation by including two Cd atoms, given with a TB/EHT consistent  $sp^3s$  Slater orbital basis as described in Section IIA.De ning

the transm ission probability is obtained as

$$T (E; j;k) = Tr_{NC1}(E; j)G_{svs}(E; j;k)_{NC2}(E;k)G_{svs}^{y}(E; j;k) :$$
(7)

The transmission function is calculated for each of the possible j;k combinations, at energy intervals of  $E = 0.01 \,\text{eV}$ . This is then processed to determ ine the statistics of T (E) as a function of the surface-site connections. O ur treatment assumes that the transfer process is entirely coherent, and as a result m ay overestim ate the observed transfer probability due to neglect of incoherent loss channels.

### III. RESULTS

### A. 1,4-dithiolbenzene

#### 1. Surface Site Dependence

The 1,4-dithiblenzene molecule, shown in Figure 1a, consists of a benzene ring with sulfur atoms attached to opposite ends of the ring, and is commonly used in molecular conduction studies. [29, 36] To begin our study, we took the MM 2 [37] molecular-dynamics optimized structure of 1,4-dithiblenzene, and replaced the thibl hydrogen atoms s with C d atoms at the appropriate bond length (2.63 A) [26], as depicted in Figure 2. In Figure 2 the solid and dashed lines indicate the average and median values of T (E), respectively. The mean, median and standard deviation of T (E) are taken over all of the 243 84 = 20412 possible connections of the 1,4-dithiblenzene molecule between surface sites of the two nanocrystals. Each calculation was taken over the -1 to 6 eV energy range, at intervals of E = 0:01 eV. In the region of -0.7 to 0 eV, the mean T (E) oscillates between values of approximately 0.13 and 0.06; the median T (E) in this region oscillates between 0.06 and 0.04. In the region of 2.4 to 3 eV, both the mean and the median T (E) reach a peak at 2.6 eV, of value 0.30 and 0.21, respectively. Prior to this peak, the mean T (E) ranges from 0.04 to 0.18 in the region of 2.4 to 2.6 eV, and from 0.10 to 0.08 in the region from 2.6 to 3 eV; the median T (E) follows the same equalitative behavior, but with lower values. The mean transmission probabilities in both of these energy ranges, corresponding to the hole and electron transmission probabilities, are similar to those determined by M eier et al. from their analysis of the TRFR data.[12] Note that the latter was non-microscopic and employed a t to the experimental results.

#### 2. Role of the Energy Scale Shift

As mentioned in Section IIA, the absolute energy scales of the TB and EHT Ham iltonians are not the same, requiring an energy shift to make them consistent. By calculating the average di erence between the S and Se atom ic orbital ionization potentials (diagonal Ham iltonian matrix elements) obtained in the two di erent methods, one obtains an average shift of 11.155 eV. To explore the dependence of our results on the exact value of this energy correction, we perform ed calculations for T (E) using shift corrections in the range of 10.0 to 12.0 eV, at intervals of 0.5 eV, using the same m olecular geometry as in the previous section. We found that the changes in mean T (E) due to the di erent choices of energy shift lie within the variation due to surface site attachment for calculations m adee with a shift of 11.155 eV, with the exception of some peaks in the nanocrystal band gap region and in the region below -0.75 eV (in the TB param eterization, 0 eV corresponds to the highest occupied molecular orbital). These results indicate that the exact value of this shift is unim portant for band edge electrons and holes, com pared to the e ects of variation due to the surface site attachment of the molecule.

#### 3. Conform ational Dependendence

P revious theoretical studies of thiolated m olecules between gold contacts by K omilovitch and B ratkovsky indicate a strong dependence of the transmission function on the conformation of the molecule, due to the directionality of the p-type atom ic orbital interactions between m olecule and contact atom s. [29, 36] This conform ational dependence was conjectured by 0 uyang and A w schalom to be responsible for the tem perature dependence of the spin transfer observed in the experim ental study.[10] This is straightforward to study within the current microscopic theory. We rst exam ined the case in which both of C-S and S-C d bonds are collinear in the plane of the benzene ring, shown in Figure 3. Such conformation shows a decrease in both the hole and electron region T (E) values below 0:05. Next we exam ined the e ects of moving the S-C d bond in the plane and out of the plane of the benzene ring, show n respectively in Figures 4 and 5. For the in-plane motions, the value of T (E) below 2.5 eV remains relatively constant, and the region between 4-5 eV shows the greatest changes. W hen one of the C d-S bonds was approximately collinear with the S-C bond, the e ect due to moving the other bond was negligible com pared to the case of both Cd-S colinear with their respective S-C bonds. Bends of both C-S-C d linkages were required to obtain an enhancement in T (E). For the out of benzene plane motions, shown in Figure 5, we found enhancements in T (E) in the range of -1 to +0.5eV, with changes in the 4 to 5 eV range only for the extrem e angles. As seen in the qure, the T (E) for the hole reached a maximum of 0.25. We note that the transmission probability for the hole is dependent on the out of plane component of the C-S-Cd dihedral angle, while the electron transmission probability is dependent on the in-plane angle.

#### B. 1,4-dithiolcyclohexane

As shown in Figure 1b, 1,4-dithiolcyclohexane di ers from dithiolbenzene by the absence of pibonding between carbon atoms in the ring (due to bonding with additional hydrogen atoms making it a saturated molecule), which in turn decreases its conductivity. Just as for the 1,4-dithiolbenzene discussed in Section IIIA 1, we began with the M M 2 optimized structure for 1,4-dithiolcyclohexane. The results for this initial conformation (the so-called \boat" conformation [38] of cyclohexane) are shown in Figure 6. In the region of -1 to 0 eV and 2 to 3 eV we found the mean T (E) to be less than 0.01, with the exception of peaks at 2.6 eV and 2.8 eV, where T (E) rises to 0.04. We then performed all of the C -S-C d rotations that were carried out in Section IIIA 3 for 1,4-dithiolbenzene. The mean T (E) determined in each of these calculations is plotted as a separate line in Figure 7. From this it is evident that T (E) for this saturated linking molecule is insensitive to conform ational changes in the valence and conduction band edge energy regions, remaining near zero for all cases. This is consistent with the experimental results reported by O uyang and A w schalom .[10] The com parison to 1,4-dithiolcyclobenzene is discussed in detail in Section IV B.

### C. 2,6-dithiolnaphthalene

D ithiohaphthalene consists of two arom atic rings joined at an edge. We considered two placements of the thiol groups on this ring structure in order to investigate the e ect of length of the arom atic linker and the possibility of quantum interference e ects. The rst placement corresponds to 2,6-dithiohaphthalene, shown in Figure 1c. The ring structure was MM 2 optimized, and the C-S-C d conformation was set to the maximal T (E) conformation determined in Section IIIA 3 for 1,4-dithiolbenzene. Due to the higher computational costs as a result of the larger molecule size, we exam ined only the cases depicted in the cartoon in Figure 8, in which both C-S-C d dihedral angles with respect to the plane of the naphthalene ring were oriented in the same direction and in the opposite direction (denoted \up, up" and \up, down", respectively), and the case of the C-S-C d angle in the plane of the ring (denoted \ at"). As shown in Figure 8, T (E) in the regions of -1 to 0 eV and 2.0 to 3.5 eV are near zero for all of the conform ations we exam ined. In the energy range between 4 to 5 eV, the bent conform ation with both C-S-C d units oriented in the sam e direction was found to have a peak T (E) of 0.07, as com pared to 0.12 for the conform ation with the C-S-C d units in opposite directions.

### D. 2,7-dithiolnaphthalene

W e exam ined the analogous conform ations as described in the previous section for the 2,7-dithiolnaphthalene linked nanocrystals, shown in Figure 1d, and in the cartoons in Figure IIID. As shown in Figure 9, T (E) in the region of -1 to 0 eV varies between 0.09 and 0.02 for the bent conform ations, and 0.01 to zero for the at conform ation. In the 2.0 to 4.0 eV range, allm ean T (E) values are near zero. Both conform ations have similarm ean T (E) values over the

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entire energy range, and unlike the 2,6-dithiolnaphthalene discussed above, the variation in T (E) due to surface site attachment was also found to be similar for both bent conformations. A detailed analysis of the dierence in T (E) for the two substituted naphthalene molecules is presented in Section IV D below.

### IV. DISCUSSION

### A. Surface Site Dependence

The variations in T (E) due to the speci c surface site attachments, discussed in Section IIIA 1, and observed in all of the calculations described subsequently, presents a quality-control problem for the construction of individual spin-manipulating devices such as required for quantum computation. While the ensemble of molecularly linked nanocrystals observed in optical experiments will have a non-negligible spin transfer percentage, any particular device may have much better (or much worse) performance. However, there may be chemical elects during the assembly process which preferentially select a subset of surface sites for binding to the molecule. A itemately, use of highly symmetric nanocrystals, such as the icosahedralSinanocrystals recently predicted by Zhao et al.,[39]m ay also sim plify the problem by reducing the number of possible surface sites available for attachment. In any case, we conclude that it is essential to understand the elect of variability in surface site linkage on the coherent spin transfer probability.

### B. Comparison of Theoretical and Experimental Results for 1,4-dithiolbenzene and 1,4-dithiolcyclohexane

The results presented in Section IIIA with Section IIIB agree with the measurements of O uyang and Aw schalom (10-20% transfer for dithiolbenzene, no transfer for dithiolcyclohexane) [10] and corresponding estimates by Meier et al. (6-13% for dithiolbenzene) [12]. Unlike the latter study, we have neglected the role of the coulom b contribution due to charging of the QDs, and so our computed forward and backware transfer probabilities are equivalent. Furtherm ore, since the estimate of the transfer probability in Meier et al. is derived from a tring to experimental data, it is plicitly performs an average over conformations. As we discuss in the next section, this can lead to changes in the transfer probability. Consequently we can only expect qualitative agreement from calculations for a single conformation. Nevertheless, our calculation of negligible valence and conduction carrier transfer for the dithiolcyclohexane linked region shows the qualitative bene t of the atom istic approach, and suggests that this approach may be useful to provide parameters form odel studies in future work.

## C. Conform ation as a M echanism for Tem perature D ependence

O ur results results for the conform ational dependence of T (E), shown in Figures 3-5, are consistent with the explanation of tem perature dependence of TRFR put forward by O uyang and A w schalom, [10] namely, that di erent m olecular conform ations populated as a function of tem perature can exhibit di erent spin transfer properties. In addition to conform ational dependence, therm ally populated vibrationalm odes may play a role in the tem perature dependence. We have neglected explicit coupling of the electronic modes to vibrational modes here, although in principle the method may be extended to treat this.[35, 40, 41] We suggest that this may be studied experimentally by means of isotopically-substituted linking molecules. If the tem perature dependence is primarily due to them olecular conform ation, the isotopic substitutions will have only a smalle ect on the observed spin transfer. A Itemately, if the tem perature dependence is due to population of some subset of vibrational states, selectively isotopically substituted linkerm olecules could then be used to identify which vibrationalm odes play a dom inant role, by making use of isotope e ects on vibrational frequencies.

### D. Quantum Interference E ects

B aer and N euhauser dem onstrated that the phase coherence (or anticoherence) through a molecular ring can be used as a molecular XOR switch.[42, 43] In a simple Huckelm odel at half-lling, the wavefunction changes sign at every second site, giving rise to coherent transfer when the lengths of the two complem entary portions of the ring di er by 2n sites, and resulting in \anti-coherent" transfer when the corresponding lengths di er by 2n + 2 sites. This e ect has also been demonstrated in density-functional calculations of polycyclic hydrocarbon molecules.[44] In Section IIIC and Section IIID we predict that this di erence between coherent and anticoherent transfer for di erent loop lengths should be visible in the substituted naphthalene-linked nanocrystals. In terms of the Huckelm odel

described above, this can be understood by counting the number of carbon atom s between the thiol groups for the naphthalene m olecules shown in Figure 1c and 1d, traversing the upper and low er portions of the ring. For the 2,6-dithiohaphthalene m olecule shown in Figure 1c, there is a di erence of two sites for the upper and low er paths, resulting in destructive interference. For the 2,7-dithiohaphthalene m olecule shown in Figure 1d, the lengths of the upper and low er paths between the thiol groups is the same, resulting in constructive interference. This suggests an experimental test of the coherent transport mechanism proposed by M eier et al.,[12] that was taken as a given ansatz in this work. Speci cally, an observation of signi cant spin-transfer between 2,7-substituted naphtalene linked nanocrystals without signi cant transfer for 2,6-substituted naphtalene linked nanocrystals would provide positive evidence that hole conduction occurs through the molecule. Furtherm ore, we note that extending the distance between the nanocrystals to approximately 12.9 A as is the case with the naphthalene linker, and noting persistence of substantial spin transfer, would provide further evidence against the possibility of Forster-like[11] spin transfer mechanism s.

#### V. SUMMARY

We have developed an atom istic sem iem pirical theory for the coherent transfer of carriers between m olecularly linked nanocrystals. Our results for 1,4-dithiolbenzene and 1,4-dithiolcyclohexane linked nanocrystals are in qualitative agreement with both experimental[10] and empirical model theoretical[12] work on these systems. Using an atom istic approach, based on a sem iempirical tight-binding description of the nanocrystals, and extended Huckel theory description of the linker molecules, and a G reen's function formalism for the description of the transfer probability, we exam ined the role of surface site attachment and linking molecule conformation on the coherent transfer probability. The variation due to the former is a new insight which may be overlooked in ensemble measurements; our calculations indicate a standard deviation in T (E) due to surface site attachments of 0.1-0.2. The variation due to the latter supports the hypothesis of O uyang and Aw schalom that the temperature dependence of the spin transfer results from conformational changes in the linking molecule. In addition, we have predicted a quantum interference e ect in the coherent transfer probabilities for 2,6-dithiolnaphthalene and 2,7-dithiolnaphthalene linked nanocrystals, which we propose be used as an experimental test of the coherent nature of the transfer.

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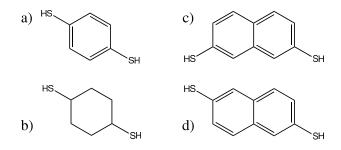


FIG.1: Linking molecules treated in this study: a) 1,4-dithiolbenzene; b) 1,4-dithiolcyclohexane; c) 2,6-dithiolnaphthalene; d) 2,7-dithiolnaphthalene.

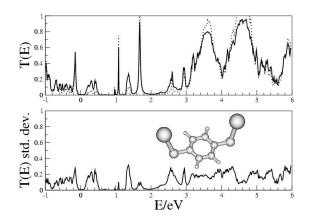


FIG. 2: T (E) (top) and standard deviation of T (E) (bottom) for 1,4-dithiolbenzene linked C dSe nanocrystals of 3.4 nm and 5.0 nm diam eter. The M M 2 optim ized conform ation of the molecule used in this calculation is shown as the inset cartoon. The black solid and black dashed lines indicate the average and median T (E), respectively. The standard deviation of T (E) results from variations due to the molecule-nanocrystal surface site attachments, as described in Section IIIA 1. The mean value of T (E) in the conduction band region (-0.7 - 0 eV) oscillates between 0.06-0.13. Peaks in T (E) in the bandgap region (0-2.4 eV) results from articial surface states due to ligand rem oval in the calculation of G (E).

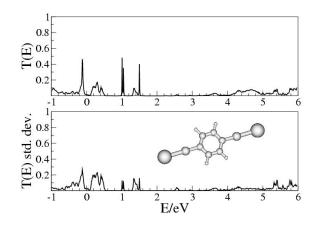


FIG. 3: T (E) for the at conformation of the 1,4-dithiolbenzene linker molecule, in which both the C-S and S-C d bond are collinear in the plane of the benzene ring. The upper gure shows mean T (E) and the lower gure the standard deviation, due to the variability in surface site attachment. As compared to the reference conformation in Figure 2, the hole energy region transfer probabilities are reduced by half, and the electron energy region T (E) is nearly zero.

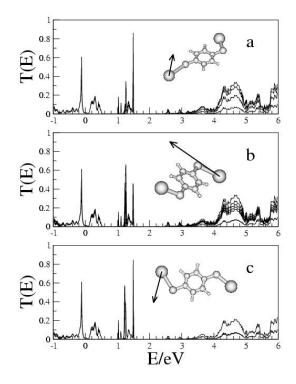


FIG. 4: E ect on T (E) of in-plane bond angle changes from the at conformation of 1,4-dithiolbenzene linked nanocrystals. A rrows from the molecule indicate the direction of the motion studied; each line in the plots indicates a di erent conformation along that direction.

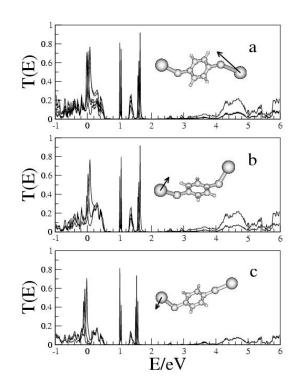


FIG.5: E ect on T (E) of out-of-plane bond angle changes from the at conform ation of 1,4-dithiolbenzene linked nanocrystals. A rrows from the molecule indicate the direction of the motion studied; each line in the three plots indicates a di erent conform ation along that direction.

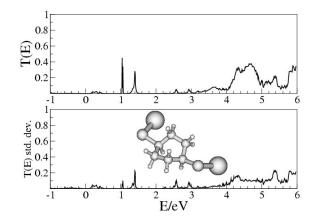


FIG.6: Mean T (E) and standard deviation for the M M 2-optim ized (boat") conformation of 1,4-dithiolcyclohexane linked nanocrystals. Note the dramatic decrease in T (E) over the entire energy range as compared with the conjugated linking m olecule 1,4-dithiolbenzene, shown in Figure 2.

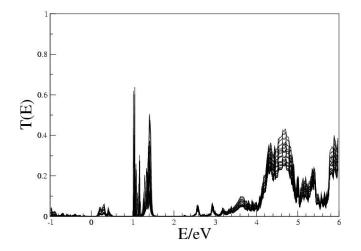


FIG.7: E ect of C-S and S-Cd bond rotations on the transmission probability, T (E), for 1,4-dithiolcyclohexane. The results for each C-S and S-Cd rotation calculated as described in Section IIIB are shown as individual lines in the gure. No signi cant changes in T (E) are observed for any of these rotationalm otions.

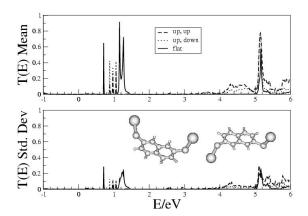


FIG. 8: Mean T (E) and surface size standard deviation for 2,6-dithiolnaphthalene linked nanocrystals. In the ranges of E = 1 ! 0 eV and E = 2:0 ! 3:5 eV, T (E) was found to be near zero for all three conformations. This results from destructive quantum interference of the electron paths, as discussed in detail in Section IV D.

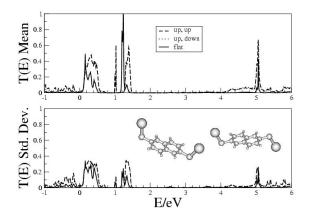


FIG.9: M ean T (E) and surface site standard deviation for 2,7-dithiohaphthalene linked nanocrystals. In contrast to the result for 2,6-dithiohaphthalene shown in Figure 8, constructive quantum interference of the electron paths causes a non-zero T (E) of between 0.02 to 0.09 in the region of E = 1! 0eV that is evident for all three conform ations.